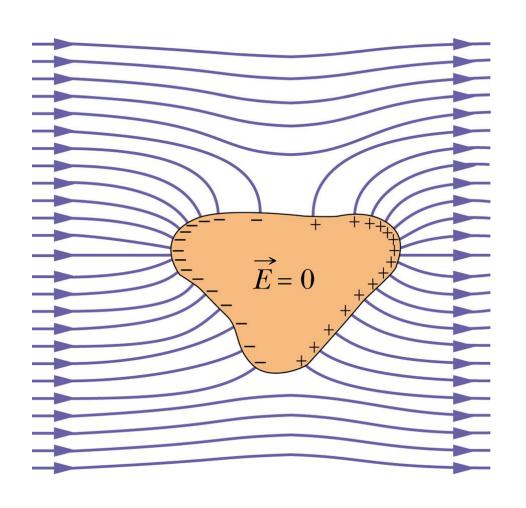
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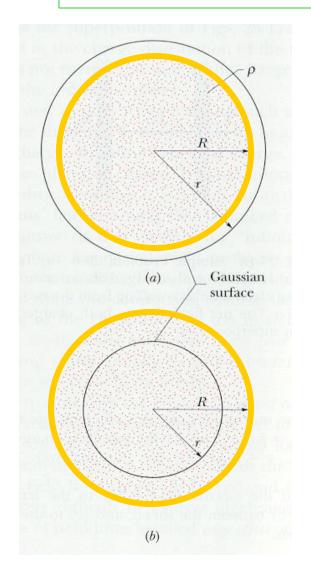
- The images and the pictures in this lecture are provided by the CDs accompanied by the books
 - 1. University Physics, Bauer and Westfall, McGraw-Hill, 2011.
 - 2. Principles of Physics, Halliday, Resnick, and Walker, Wiley, 8th and 9th Ed.
- The rest is made by me.

Isolated conductor in an external E



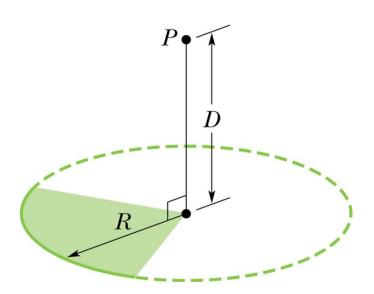
Surface of a conductor is an equipotential surface, hence normal to the electric field.

Insulating sphere

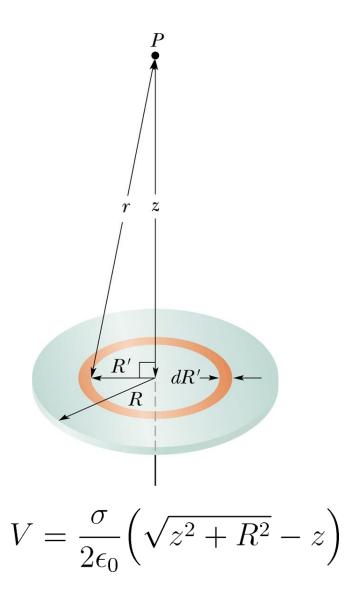


$$r > R;$$
 $E = \frac{1}{4\pi\varepsilon_0} \frac{q}{r^2}$

$$r < R$$
, $E = \frac{1}{4\pi\varepsilon_0} \frac{q}{R^3} r$

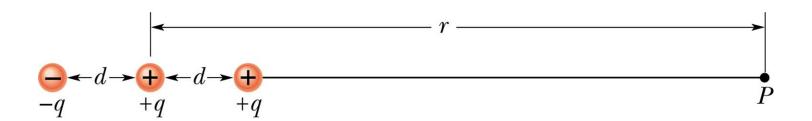


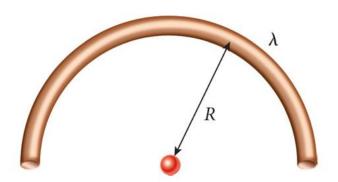
Surface charge

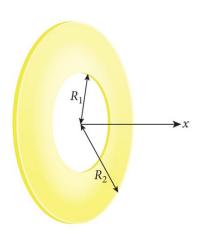


반지름 R인 부도체 구에 전하 q가 균일하게 분포되 었을 때의 퍼텐셜에너지는?

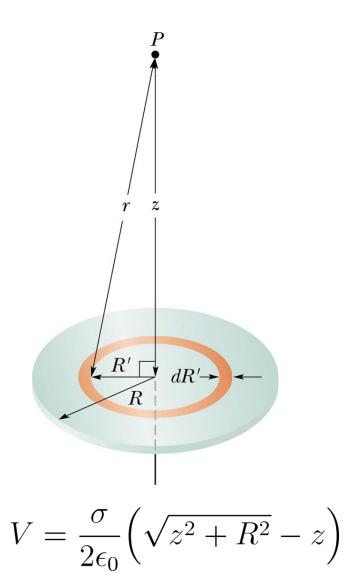
$$U = \frac{1}{4\pi\epsilon_0} \frac{3q^2}{5R}$$

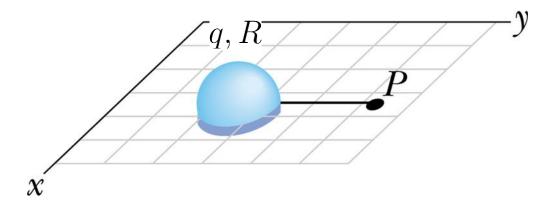






Surface charge





Chap 24. Capacitors

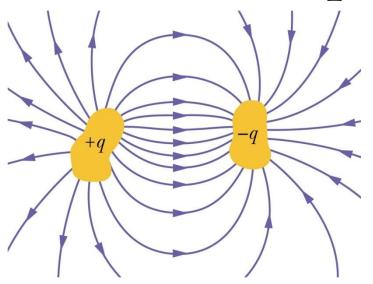


Topics in chapter 24

- (1) Concepts of capacitor and capacitance
- (2) Computation of capacitance: parallel plate, cylinder, circle, sphere
- (3) parallel and series connections of capacitors
- (4) Calculation of the electric energy stored in a capacitor: energy density of an electric field
- (5) Capacitor with dielectric material:

 electric property of dielectric material and dielectric constant

Capacitance



Capacitor

전기적으로 고립되어 있는 떨어 져 있는 두 도체

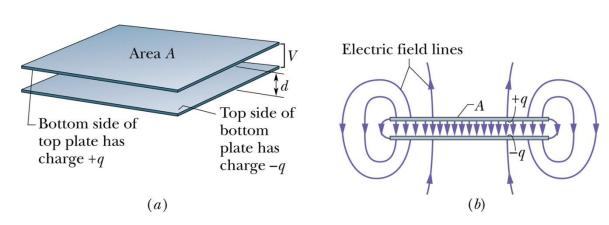
$$q = CV$$

C capacitance

SI unit

1 farad = 1 F = 1
$$C/V$$

- 1. Electric charges reside on the surface.
- 2. Conductor surfaces are equipotential surfaces.

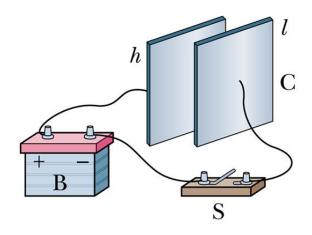


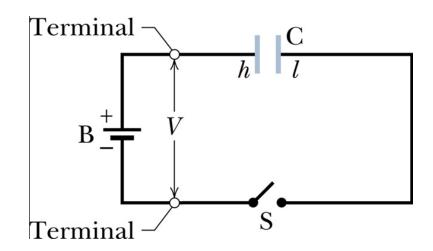
Electric capacitance can be always written in a form $C = \epsilon_0 L$.

$$\epsilon_0 = 8.85 \times 10^{-12} \text{C}^2/\text{N} \cdot \text{m}^2$$

This can be written as follows:

$$\epsilon_0 = 8.85 \times 10^{-12} \text{F/m} = 8.85 \text{pF/m}$$





Computation of capacitance

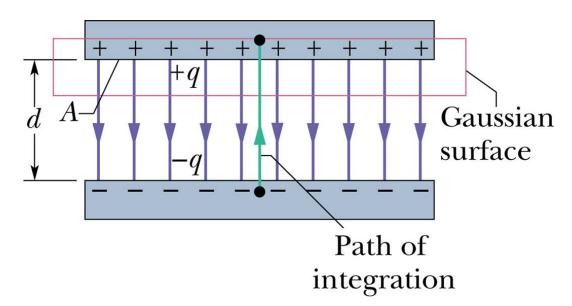
- 1. 도체 한 쪽에 전하 q, 다른 쪽에 전하 -q를 놓는다.
- 2. 두 전하 사이의 electric field를 계산한다.
- 3. Potential difference를 구한다.

Electric field
$$\epsilon_0 \oint \vec{E} \cdot d\vec{A} = q$$

Electric potential $V_f - V_i = -\int_i^J \vec{E} \cdot d\vec{s}$ difference

$$C = \frac{q}{|\Delta V|}$$

Parallel capacitor

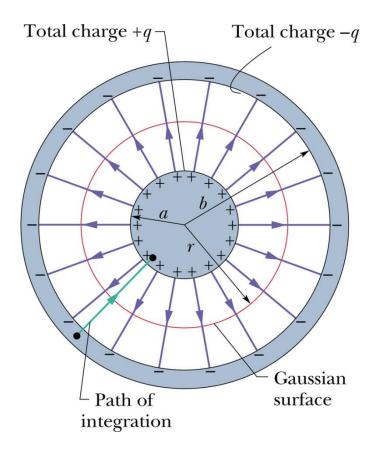


$$\epsilon_0 \oint \vec{E} \cdot d\vec{A} = q \longrightarrow q = \epsilon_0 E A$$

$$V_f - V_i = -\int_i^f \vec{E} \cdot d\vec{s} \longrightarrow V = \int_-^+ E ds = E \int_-^+ ds = E d$$

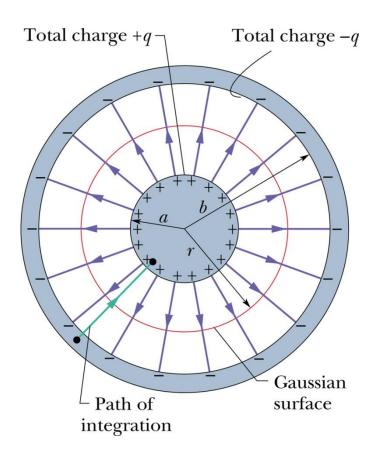
$$C = \frac{\epsilon_0 A}{d}$$

Cylindrical capacitor



$$C = 2\pi\epsilon_0 \frac{L}{\ln(b/a)}$$

Spherical capacitor



$$C = 4\pi\epsilon_0 \frac{ab}{b-a}$$

고립된 공
$$C=4\pi\epsilon_0R$$